



## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
-40V	80mΩ @ V <sub>GS</sub> = -10V	-3.4A
	100mΩ @ V <sub>GS</sub> = -4.5V	-3.0A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Battery Charging
- Power Management Functions
- DC-DC Converters
- Portable Power Adaptors

## **40V P-CHANNEL ENHANCEMENT MODE MOSFET**

# **Features and Benefits**

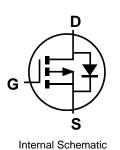
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- PPAP Capable (Note 4)

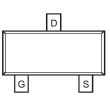
# **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



Top View





Top View

# Ordering Information (Note 5)

Part Number	Case	Packaging
DMP4065SQ-7	SOT23	3,000/Tape & Reel
DMP4065SQ-13	SOT23	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

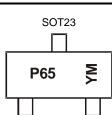
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# Marking Information



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P65 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: E = 2017) M = Month (ex: 9 = September)

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Date Code Key											
Year	2014	4	2015		2016	20	17	2018		2019	
Code	В		С		D	E		F		G	
<b>NA</b> (1		= .		•							
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aua	Sep	Oct	Nov

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SOT23



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	-40	V	
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
Continuous Drain Current (Note 6) $V_{GS}$ = -10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	-2.4 -1.9	A
Continuous Drain Current (Note 7) $V_{GS} = -10V$ State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		ID	-3.4 -2.7	А	
Pulsed Drain Current			IDM	-20	A
Avalanche Current, L = 0.1mH	I <sub>AS</sub>	-14	A		
Avalanche Energy, L = 0.1mH		E <sub>AS</sub>	9.8	mJ	

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	0.72	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 6)	R <sub>θJA</sub>	171	°C/W
Power Dissipation (Note 7)	PD	1.4	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6)	R <sub>0JA</sub>	90	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-40	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>		—	-1.0	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.0	_	-3.0	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Proven		64	80	mΩ	$V_{GS} = -10V, I_D = -4.2A$	
	R <sub>DS(ON)</sub>		85	100	11122	$V_{GS} = -4.5V, I_D = -3.3A$	
Diode Forward Voltage	V <sub>SD</sub>		-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	—	587	—	pF		
Output Capacitance	Coss	_	88	—	pF	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss		40	—	pF		
Gate Resistance	Rg		14.4	—	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	6.1	—	nC		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg		12.2	-	nC	$V_{DS} = -20V, I_{D} = -4.2A$	
Gate-Source Charge	Q <sub>gs</sub>	_	1.8	—	nC	$v_{\rm DS} = -20v, \ I_{\rm D} = -4.2A$	
Gate-Drain Charge	Q <sub>gd</sub>	_	2.4	—	nC	1	
Turn-On Delay Time	t <sub>D(ON)</sub>		3.6	—	ns		
Turn-On Rise Time	t <sub>R</sub>		2.9	—	ns	$V_{DD} = -15V, V_{GS} = -10V,$	
Turn-Off Delay Time	tD(OFF)		36.3	—	ns	$I_D = -1.0A$ , $R_G = 6\Omega$	
Turn-Off Fall Time	t <sub>F</sub>		15.3	_	ns		

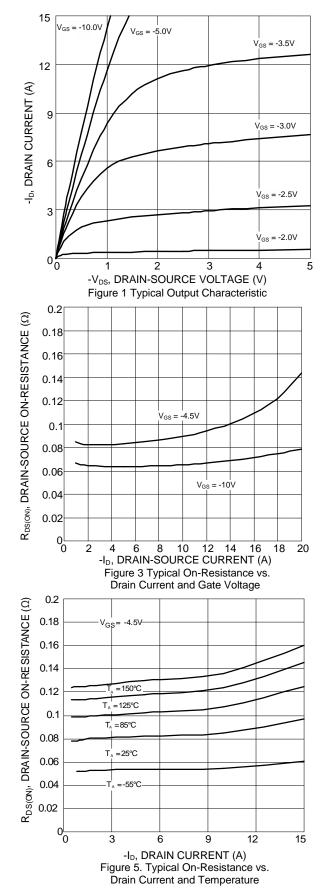
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

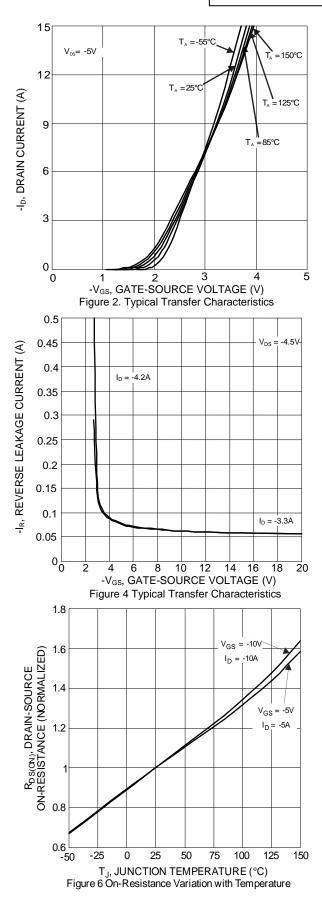
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.



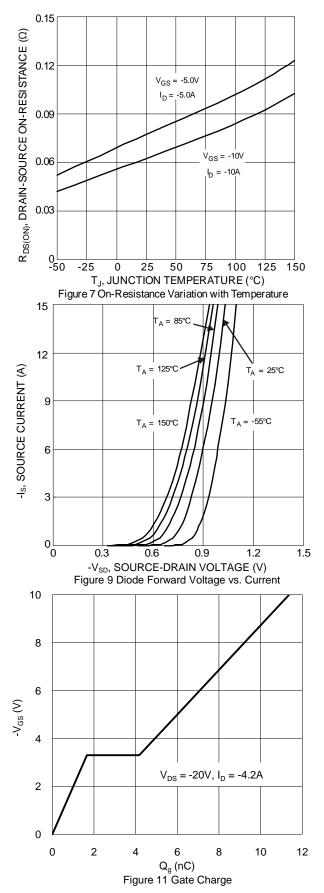
# **DMP4065SQ**

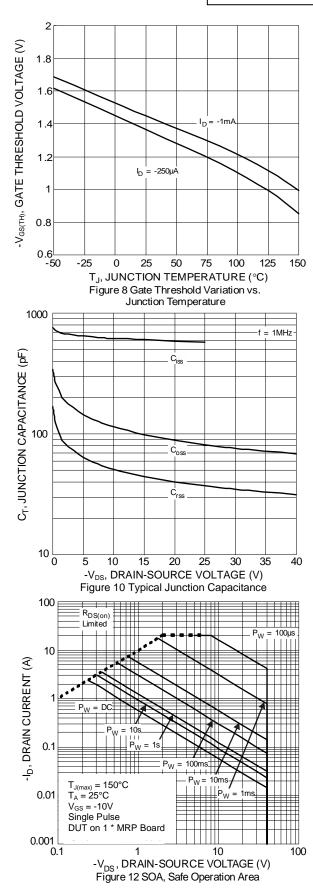




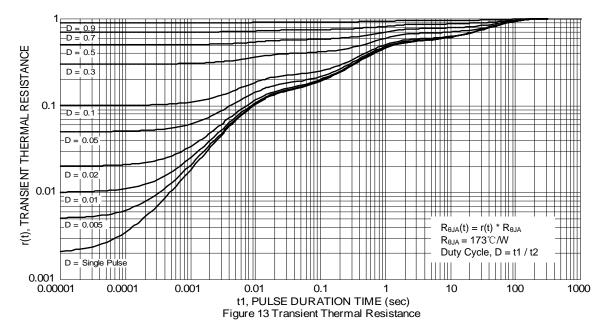








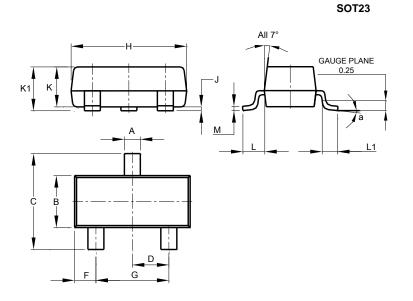






# **Package Outline Dimensions**

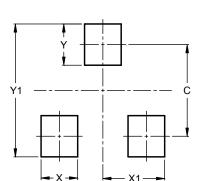
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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